



DMN6069SFG

## **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>C</sub> = +25°C
60V	$50m\Omega @ V_{GS} = 10V$	18A
000	63mΩ @ V <sub>GS</sub> = 4.5V	16A

# **Description and Applications**

This MOSFET is designed to minimize the on-state resistance  $(R_{DS(ON)})$ , yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Backlighting
- Power Management Functions
- DC-DC Converters

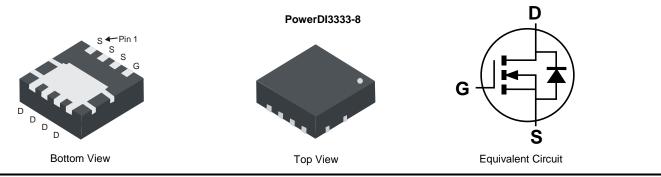
## 60V N-CHANNEL ENHANCEMENT MODE MOSFET POWERDI

## **Features and Benefits**

- Low R<sub>DS(ON)</sub> Ensures On-State Losses are Minimized
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products (PowerDI<sup>®</sup>)
- Occupies Just 33% of the Board Area Occupied by SO-8 Enabling Smaller End Product
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

- Case: PowerDI3333-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 🕼
- Weight: 0.03 grams (Approximate)



# Ordering Information (Note 4)

Part Number	Case	Packaging
DMN6069SFG-7	PowerDI3333-8	2,000/Tape & Reel
DMN6069SFG-13	PowerDI3333-8	3,000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**

Notes:



N69 = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 16 = 2016) WW = Week Code (01 to 53)



### Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units		
Drain-Source Voltage		V <sub>DSS</sub>	60	V	
Gate-Source Voltage			V <sub>GSS</sub>	±20	V
Continuous Drain Current (Note 6) $V_{GS}$ = 10V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	5.6 4.5	А
	Steady State	T <sub>C</sub> = +25°C T <sub>C</sub> = +70°C	ID	18 14.5	А
Pulsed Drain Current (380µs Pulse, Duty Cycle = 1%)			I <sub>DM</sub>	25	А
Maximum Continuous Body Diode Forward Current (Note 6)			Is	2.5	А
Avalanche Current (Note 7) L = 0.1mH			I <sub>AS</sub>	12	А
Avalanche Energy (Note 7) L = 0.1mH			E <sub>AS</sub>	7.2	mJ

## **Thermal Characteristics**

Characteristic	Symbol	Value	Units	
Total Power Dissipation (Note 5)	PD	0.93	W	
Thermal Deviatorses Junction to Ambient (Note 5)	Steady State	P	134	°C/W
Thermal Resistance, Junction to Ambient (Note 5)	t<10s	$R_{\theta JA}$	82	
Total Power Dissipation (Note 6)		PD	2.4	W
Thermal Desistance, Junction to Ambient (Note 6)	Steady State	P	53	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	R <sub>0JA</sub>	33	
Thermal Resistance, Junction to Case	R <sub>θJC</sub>	5		
Operating and Storage Temperature Range		TJ. TSTG	-55 to +150	°C

# Electrical Characteristics (T<sub>A</sub> = +25°C, unless otherwise specified.)

-		1			•	-	
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)	-		I	1		1	
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	60	—	—	V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current T <sub>J</sub> = +25°C	I <sub>DSS</sub>	_		1	μA	$V_{DS} = 60V, V_{GS} = 0V$	
Zero Gate Voltage Drain Current T <sub>J</sub> = +150°C (Note 9)	IDSS	_	—	100	μA	$V_{DS} = 60V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS	_		±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)			-				
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1		3	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	Proven	_	39	50	mΩ	$V_{GS} = 10V, I_D = 4.5A$	
	R <sub>DS(ON)</sub>	_	47	63	11152	$V_{GS} = 4.5V, I_D = 3A$	
Diode Forward Voltage	V <sub>SD</sub>	_	—	1.1	V	$V_{GS} = 0V, I_{S} = 2.5A$	
On State Drain Current (Note 9)	I <sub>D(ON)</sub>	20	—	—	А	$V_{DS} \ge 5V, V_{GS} = 10V$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	CISS	—	740	1,480	pF		
Output Capacitance	Coss	_	40	80	pF	$V_{DS} = 30V, V_{GS} = 0V,$ - f = 1.0MHz	
Reverse Transfer Capacitance	C <sub>RSS</sub>	_	28	55	pF		
Gate Resistance	RG	_	2.2	4	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Q <sub>G</sub>	_	6.4	12	nC		
Total Gate Charge (V <sub>GS</sub> = 10V)	Q <sub>G</sub>	_	14	25	nC		
Gate-Source Charge	Q <sub>GS</sub>	_	2.8	5.5	nC	$V_{DS} = 30V, I_D = 12A$	
Gate-Drain Charge	Q <sub>GD</sub>	_	2.3	5	nC		
Turn-On Delay Time	t <sub>D(ON)</sub>	_	3.6	10	ns		
Turn-On Rise Time	t <sub>R</sub>		5.0	10	ns	$V_{DS} = 30V, I_{D} = 12A$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	12	24	ns	$V_{GS} = 10V, R_G = 6.0\Omega$	
Turn-Off Fall Time	t <sub>F</sub>		3.3	10	ns	7	
Body Diode Reverse Recovery Time	t <sub>RR</sub>	_	11	22	ns		
Body Diode Reverse Recovery Charge	Q <sub>RR</sub>		5.1	10	nC	- I <sub>F</sub> = 4.5A, di/dt = 100A/μs	

Notes: 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.

6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.

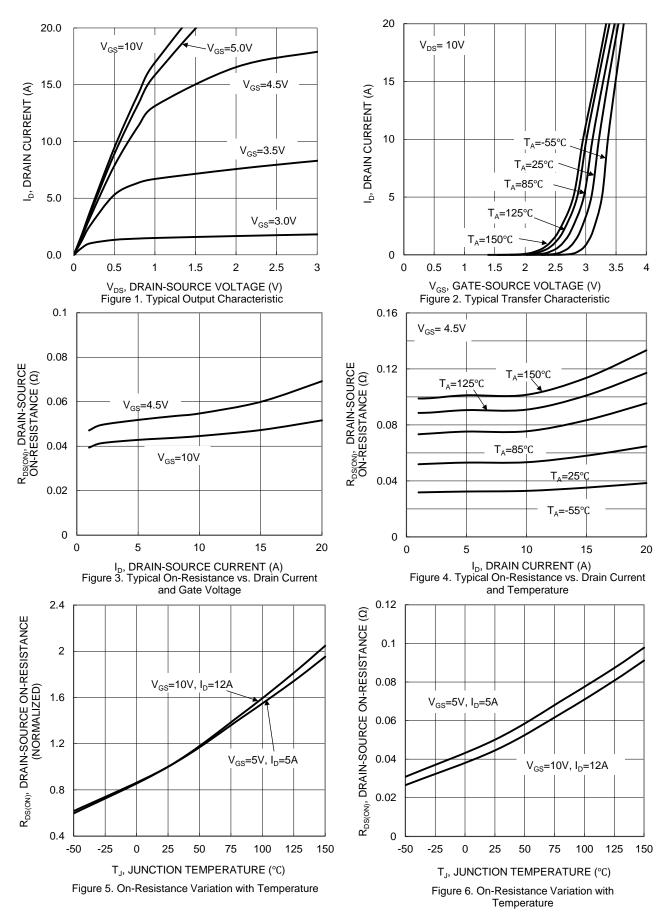
7. I<sub>AS</sub> and E<sub>AS</sub> ratings are based on low frequency and duty cycles to keep  $T_J$  = +25°C.

8. Short duration pulse test used to minimize self-heating effect.

9. Guaranteed by design. Not subject to product testing.

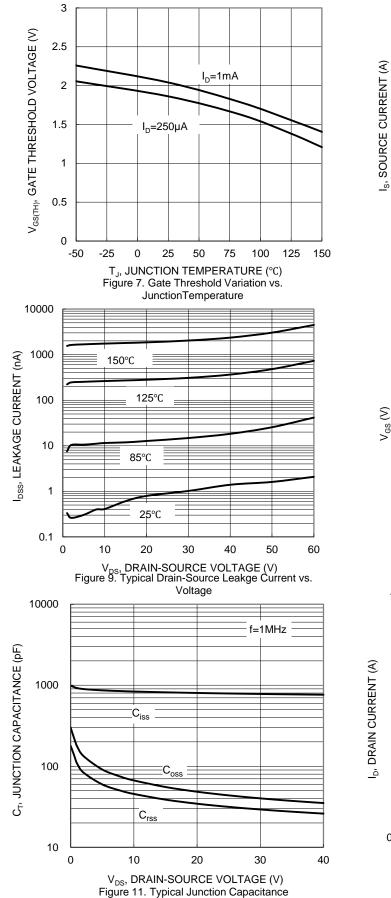
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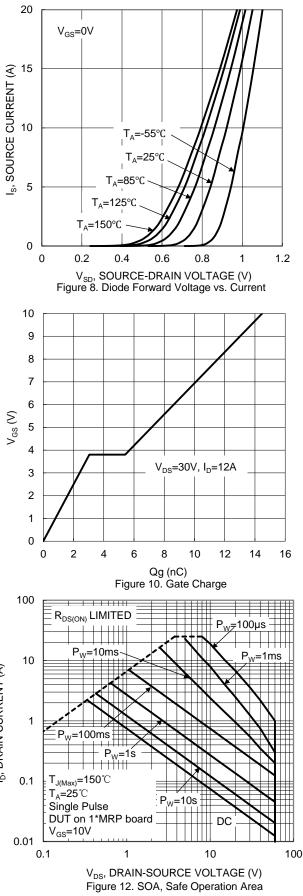






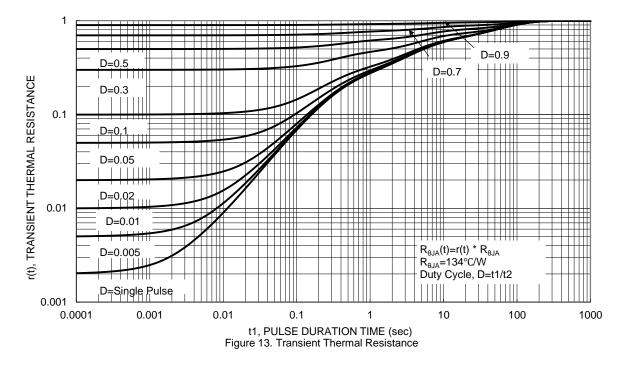
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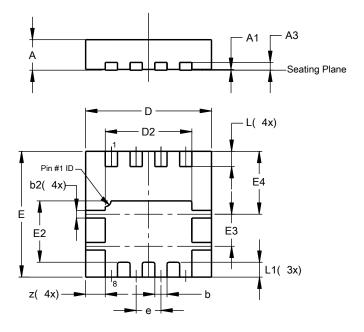






# Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

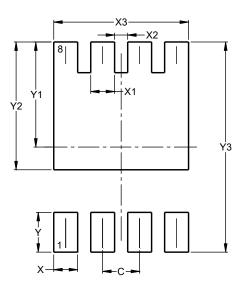


PowerDI3333-8						
Dim	Min	Min Max				
Α	0.75	0.85	0.80			
A1	0.00	0.05	0.02			
A3	-	-	0.203			
b	0.27	0.37	0.32			
b2	0.15	0.25	0.20			
D	3.25	3.35	3.30			
D2	2.22	2.32	2.27			
E	3.25	3.35	3.30			
E2	1.56	1.66	1.61			
E3	0.79	0.89	0.84			
E4	1.60	1.70	1.65			
е	-	-	0.65			
L	0.35	0.45	0.40			
L1	_	-	0.39			
z	_	_	0.515			
All I	All Dimensions in mm					

### PowerDI3333-8

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



PowerDI3333-8

Dimensions	Value (in mm)			
С	0.650			
Х	0.420			
X1	0.420			
X2	0.230			
X3	2.370			
Y	0.700			
Y1	1.850			
Y2	2.250			
Y3	3.700			



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